





#### 125V NPN LOW SATURATION TRANSISTOR IN SOT23

#### **Features**

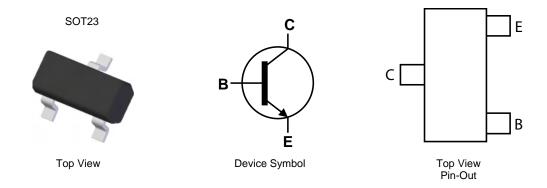
- BV<sub>CEO</sub> > 125V
- I<sub>C</sub> = 1A high Continuous Collector Current
- I<sub>CM</sub> = 3A Peak Pulse Current
- $R_{CE(sat)} = 160 \text{m}\Omega$  for a low equivalent On-Resistance
- 625mW Power dissipation
- hFE specified up to 3A for high current gain hold up
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight 0.008 grams (approximate)

#### **Applications**

- DC-DC / DC-AC Modules
- Regulator
- LED driver
- · CCFL Backlighting Inverters



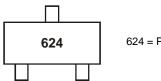
#### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FMMT624TA	624	7	8	3,000
FMMT624TC	624	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**



624 = Product Type Marking Code





### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	125	V
Collector-Emitter Voltage	V <sub>CEO</sub>	125	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ic	1	Α
Peak Pulse Current (Note 5)	I <sub>CM</sub>	3	A
Base Current	I <sub>B</sub>	500	mA

## Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_{D}$	625	mW
Power Dissipation (Note 6)	$P_{D}$	806	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	155	°C/W
Thermal Resistance, Junction to Leads (Note 7)	R <sub>0JL</sub>	194	°C/W
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C

## ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

- 5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

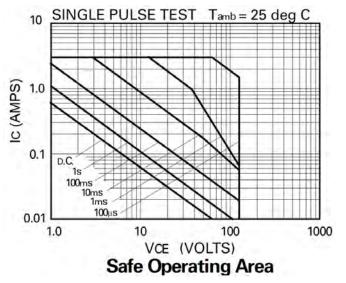
  6. Same as note 5, except the device is measured at t ≤ 5 sec.

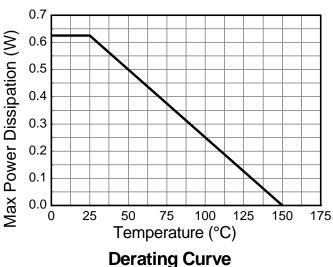
  7. Thermal resistance from junction to solder-point (at the end of the collector lead).

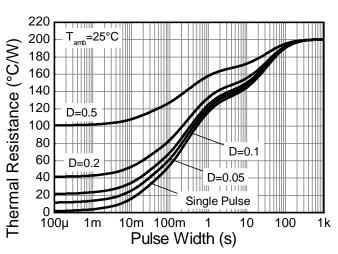
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

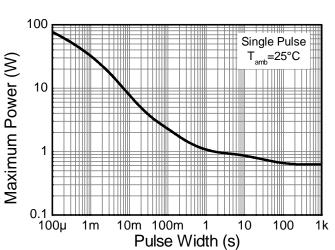


## **Thermal Characteristics and Derating information**





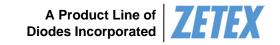




**Transient Thermal Impedance** 

**Pulse Power Dissipation** 





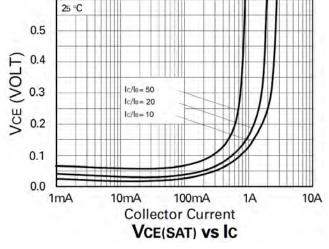
### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

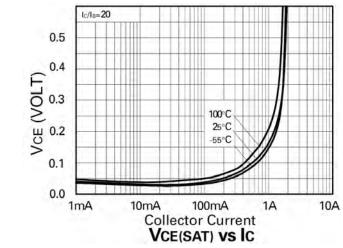
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	125	250	-	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	125	160	-	V	$I_C = 1mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.3	-	V	$I_{E} = 100 \mu A$
Collector Cut-off Current	I <sub>CBO</sub>	-	<10	100	nA	V <sub>CB</sub> = 100V
Emitter Cut-off Current	I <sub>EBO</sub>	-	<10	100	nA	V <sub>EB</sub> = 6.0V
Collector Emitter Cut-off Current	I <sub>CES</sub>	-	<10	100	nA	V <sub>CES</sub> = 100V
Static Forward Current Transfer Ratio (Note 9)	h <sub>FE</sub>	200 300 100 -	400 450 140 18	- - -	-	$I_C = 10 \text{mA}, V_{CE} = 10 \text{V}$ $I_C = 200 \text{mA}, V_{CE} = 10 \text{V}$ $I_C = 1 \text{A}, V_{CE} = 10 \text{V}$ $I_C = 3 \text{A}, V_{CE} = 10 \text{V}$
Collector-Emitter Saturation Voltage (Note 9)	VCE(sat)	- - -	26 70 160 165	50 150 220 250	mV	$I_C = 0.1A$ , $I_B = 10mA$ $I_C = 0.5A$ , $I_B = 50mA$ $I_C = 0.5A$ , $I_B = 10mA$ $I_C = 1A$ , $I_B = 50mA$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	0.85	1.0	V	$I_C = 1A$ , $I_B = 50mA$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(on)</sub>	-	0.70	1.0	V	$I_C = 1A, V_{CE} = 10V$
Transition Frequency	f <sub>T</sub>	100	155	-	MHz	$I_C = 50 \text{mA}, V_{CE} = 10 \text{V},$ f = 100 MHz
Collector Output Capacitance	C <sub>obo</sub>	-	7	15	pF	V <sub>CB</sub> = 10V, f = 1MHz
Turn-On Time	t <sub>(on)</sub>	-	60	-	ns	$V_{CC} = 50V, I_C = 0.5A,$
Turn-Off Time	t <sub>(off)</sub>	-	1300	-	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$

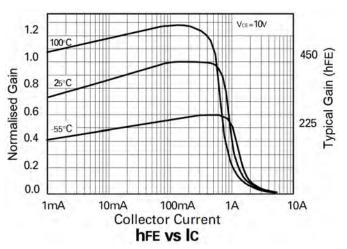
Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%

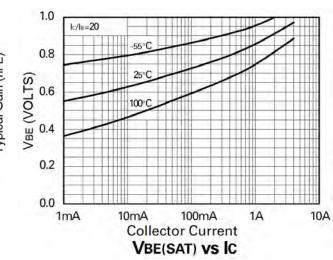


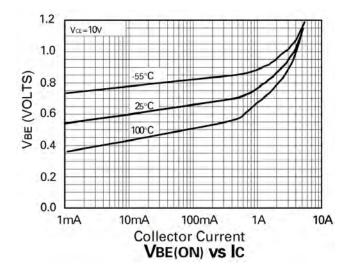
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)







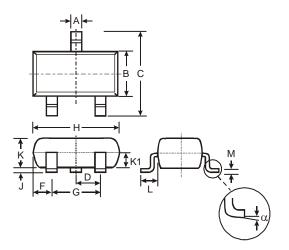






# **Package Outline Dimensions**

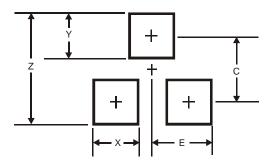
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	-	0.400		
L	0.45	0.61	0.55		
M	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
Z	2.9		
X	0.8		
Y	0.9		
С	2.0		
Е	1.35		





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